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Cu₂O/CuO photocathode with improved stability for photoelectrochemical water reduction

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P-type cuprous oxide (Cu₂O) photocathode covered with a thin layer of cupric oxide (CuO) was prepared by fast annealing a copper foil via H₂-O₂ flame. The as-prepared composite photocathode is characteristic of a junction structure formed between the (110) plane of Cu₂O and the (111) plane of CuO. The Cu₂O/CuO composite photocathode showed improved stability for photoelectrochemical (PEC) water reduction by increasing the coverage of CuO on Cu₂O.

Photoelectrochemical (PEC) water splitting has aroused considerable research interest in the past decade due to its potential for converting solar energy to hydrogen fuel.^{1,2} Semiconductors with suitable band gap (1.6-2.2 eV), good stability and low cost are highly desirable to enable this process acceptable.^{3,4} Among all the semiconductors under investigation, p-type cuprous oxide (Cu₂O) is regarded as an attractive candidate for fabricating photocathode due to its high photoactivity and natural abundance.⁵⁻⁷ The band gap of Cu₂O is *ca.* 2.1 eV, which makes it attractive for light harvesting with a theoretical photocurrent density of 14.7 mA cm⁻² and a solar-to-hydrogen conversion efficiency of 18.7% under AM 1.5 G illumination.^{8,9} However, the application of Cu₂O photocathode is limited due to the poor stability under PEC process.^{6,10}

To address the above issue, surface modification has been used to protect the photoelectrode from photocorrosion in the PEC water splitting process.¹¹⁻¹³ For example, the stability of photoelectrode could be improved by covering conducting polymers¹⁴⁻¹⁶, metal thin films¹⁷⁻¹⁹ and stable metal oxides^{13, 20, 21}. Similar efforts have been devoted to improving the stability of Cu₂O photocathode by covering suitable metal oxide layers to prevent Cu₂O photocathode from contacting with electrolyte directly.⁶ It was reported that a stable cupric oxide (CuO) layer can protect Cu₂O and provide a suitable band structure for charge transportation.^{4,10,22} However, the fabrication of Cu₂O/CuO composite photocathodes is complicated and the interfacial structure between Cu₂O and CuO is unclear up to now.

Herein, we reported a facile method to prepare Cu₂O/CuO composite photocathode by heating a copper foil in H₂-O₂ flame. The photocathode is composed of internal Cu₂O layer covered with a thin layer of CuO on the external surface and the interface between Cu₂O and CuO is characteristic of a junction formed between the (110) plane of Cu₂O and the (111) plane of CuO. With the increase of CuO coverage, the Cu₂O/CuO composite photocathode showed

improved stability for photoelectrochemical (PEC) water reduction.

Cu₂O/CuO composite photocathodes were prepared by heating a copper foil in a H₂-O₂ flame at *ca.* 1300 K for 2, 5, 10 or 15 s, which are denoted as HT-2S, HT-5S, HT-10S and HT-15S, respectively. The compositions of the as-prepared films were investigated by X-ray diffraction (XRD) technique (Fig. 1a). The diffraction peaks for all the prepared samples at 43.3 and 50.4 degree are indexed to the (111) and (200) plane of Cu, respectively (JCPDS card No. 04-0836). The peaks at 30.0, 36.7, 42.8, and 61.7 degree for HT-5S, HT-10S and HT-15S are the characteristic peaks of cubic phase Cu₂O (JCPDS card No. 78-2076). Meanwhile, the weak diffraction peaks at 35.8 and 39.0 degree for HT-10S and HT-15S are assigned to monoclinic CuO with the orientation of (111) plane (JCPDS card No. 48-1548). The much stronger diffraction peaks of Cu₂O compared with those of CuO indicated that Cu₂O is the dominant composition of the electrode. Moreover, the increased intensities for copper oxides indicate that the degree of copper oxidation and the crystallinity of copper oxides increase with prolonged heating duration.

The surface structure of the photocathodes was further characterized by Raman spectroscopy, which is more sensitive for investigating surface region.²³ In Fig. 1b, the Raman bands at 154 and 218 cm⁻¹ for HT-2S and HT-5S are assigned to Cu₂O.²⁴ The Raman bands at 292 and 324 cm⁻¹ for all the samples are the characteristic bands of CuO.²⁵ The Raman spectra illustrate that the CuO phase exists on the surface of all the as-prepared samples and increases with prolonged heating duration. The surface compositions of samples were further investigated by X-ray photoelectron spectroscopy (XPS). Fig. 1c shows the O1s XPS spectra for the as-prepared photocathodes. All the samples exhibit a lattice O1s peak of CuO at 530.3 eV and a second peak at higher binding energy of 531.8 eV associated with the surface hydroxide.²⁶ For Cu₂p_{3/2} XPS spectra in Fig. 1d, the peak located at 932.6 eV and is assigned to Cu₂p_{3/2} for Cu₂O and the peak located at 933.6 eV with two satellite peaks at 944.0 and 941.2 eV is attributed to Cu₂p_{3/2} for CuO.²⁷⁻²⁹ Therefore, both the CuO and Cu₂O phase were present on the surface of HT-2S, while mainly the CuO phase was present on the surface of HT-5S, HT-10S, and HT-15S. Combined with the Raman analysis, we can conclude that the surface of all the samples is covered by CuO and its thickness and coverage increase with prolonged heating duration.

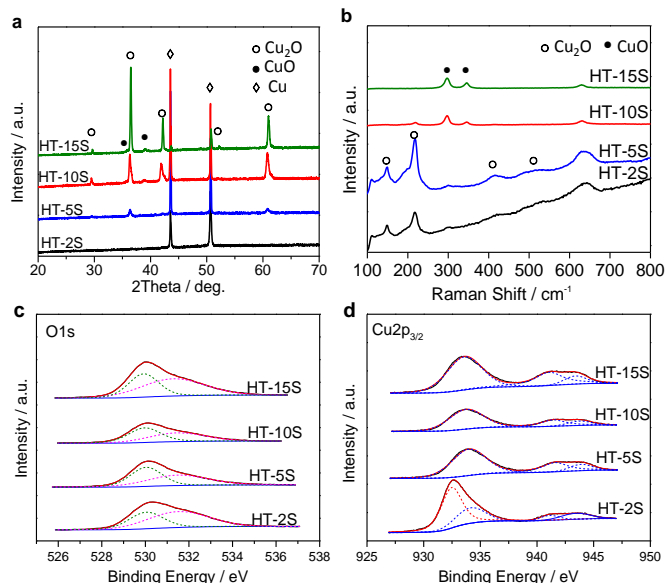


Fig. 1 XRD patterns (a), Raman spectra (b) and XPS spectra (c-d) of composite $\text{Cu}_2\text{O}/\text{CuO}$ photocathodes.

Based on the analysis above, the structure of the $\text{Cu}_2\text{O}/\text{CuO}$ composite photocathode prepared by the facile oxidation of copper foil can be confirmed. All the photocathodes were composed with low chemical oxidation state Cu_2O adjacent to the Cu substrate and high chemical state CuO layer covering the Cu_2O layer (Scheme 1). The thickness of inner Cu_2O layer and the outer CuO layer increased simultaneously as the heating process prolonged. The coverage of CuO can be increased by increasing the duration of $\text{H}_2\text{-O}_2$ flame heating, and a full coverage of CuO on Cu_2O was obtained for HT-10S and HT-15S.

To clarify the composite structure of as-prepared films, further investigation was conducted by the high resolution transmission electron microscopy (HRTEM) for HT-10S photocathode. Fig. 2a shows the electron diffraction of HT-10S photocathode in the selected region (inset in Fig. 2a). The diffraction mottle of Cu_2O (100) plane indicates that the Cu_2O formed in this work is single crystalline in micrometre scale. Fig. 2b shows the HRTEM image of the junction region between Cu_2O and CuO. The interplanar crystal spacing of 3.0 Å and 2.34 Å is ascribed to the (110) plane of Cu_2O and (111) plane of CuO, respectively. Fig. 2c shows the HRTEM image of the exposed edge of Cu_2O . It indicates that the junction region in Fig. 2b is not formed by the treatment for HRTEM measurement. The contact between the two planes indicates the transformation from Cu_2O (110) to CuO (111), which is reasonable considering the similar surface atom arrangement (Fig. 2d).^{30,31} This $\text{Cu}_2\text{O}/\text{CuO}$ structure with high crystallinity and compact contact in junction region could be beneficial for the charge transfer and protection of Cu_2O , leading to a higher and a more stable photocurrent¹⁰.

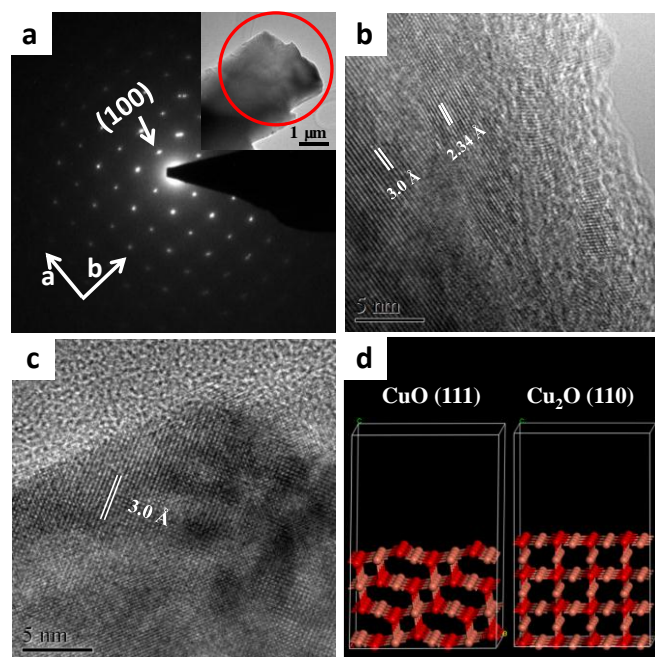


Fig. 2 The electron diffraction of HT-10S photocathode (a), the inset shows the selected region. HRTEM images of HT-10S photocathode (b, c). The surface atom arrangement of CuO (111) plane and Cu_2O (110) plane (d).

The morphologies of the as-prepared photocathodes were investigated by scanning electron microscope (SEM). As shown in Fig. 3, only small particles were found on the surface of HT-2S photocathode. When the heating duration was increased to 5 s, the small particles were agglomerated and finally formed linked and twisty nanowire network when the heating duration was increased to 10 and 15 s. According to the cross-sectional SEM images (Fig. S1†) the thickness of copper oxides of HT-5S, HT-10S and HT-15S were estimated to be *ca.* 0.26 μm, 2 μm and 3.5 μm, respectively. This also indicates that the thickness of the copper oxides increased with the prolonged heating duration, which is in good agreement with the XRD analysis. The UV-Visible diffuse reflectance spectra of the photocathodes (Fig. S2†) manifest the mixed absorption properties of Cu_2O and CuO semiconductors.³² The absorption of as-prepared samples is improved as the prolonged heating duration, which is due to the increasing amount of copper oxides.

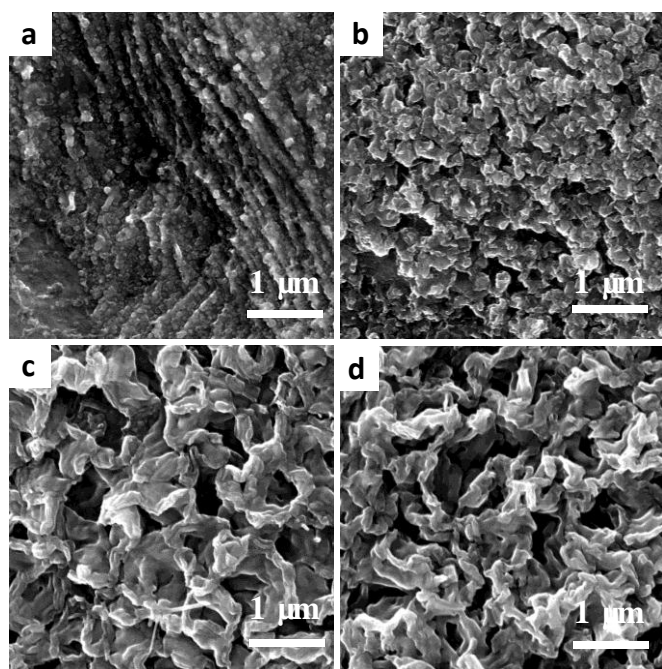


Fig. 3 SEM images of HT-2S (a), HT-5S (b), HT-10S (c) and HT-15S (d).

The PEC performances of the $\text{Cu}_2\text{O}/\text{CuO}$ composite photocathodes were evaluated at 0 V vs. RHE with chopped illumination under AM 1.5 G in 0.5 M Na_2SO_4 electrolyte (pH 6.82) with Ar bubbling. In Fig. 4a, the initial photocurrent densities of HT-2S, HT-5S, HT-10S and HT-15S at 0 V vs. RHE were -0.05, -0.11, -0.82 and -0.45 mA cm^{-2} , respectively. The improved photocurrent density for HT-10S compared with HT-2S and HT-5S could be attributed to the increase of thickness of Cu_2O oxides, which will influence the light absorption of the electrodes. The decreased current density for HT-15S compared with that for HT-10S may result from the thicker CuO layer, which will decrease the light harvesting by Cu_2O layer. Fig. 4b shows the current decay curves of as-prepared photocathodes. For HT-2S and HT-5S, the photocurrent decreased sharply to less than 20% of the initial value within 5 min. For HT-10S, the photocurrent maintains 30% of the initial value after 10 min. The HT-15S photocathode shows a more stable photocurrent with a decrease of less than 40% for 10 min. Apparently, HT-10S and HT-15S are much more stable than HT-2S and HT-5S due to the increase of the CuO coverage. Therefore, it is evident that the as-prepared $\text{Cu}_2\text{O}/\text{CuO}$ composite structure was beneficial for improving the stability of Cu_2O photocathode in PEC water reduction. We also note that among all the samples, HT-10S shows the highest initial photocurrent and HT-15S shows the best stability. This is reasonable considering the combined influence of CuO that will decrease the photoactivity and improve photostability of the present electrode. Therefore, CuO layer with proper thickness is desirable to balance the photoactivity and photostability in the $\text{Cu}_2\text{O}/\text{CuO}$ composite system.

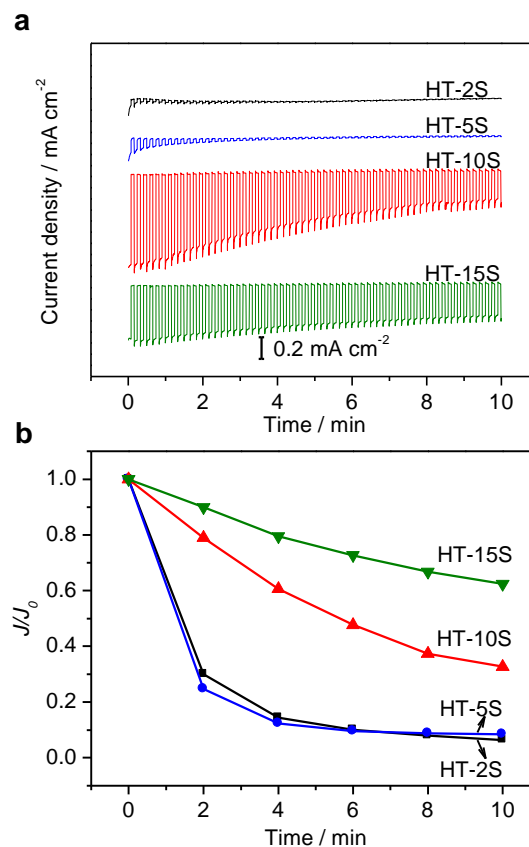
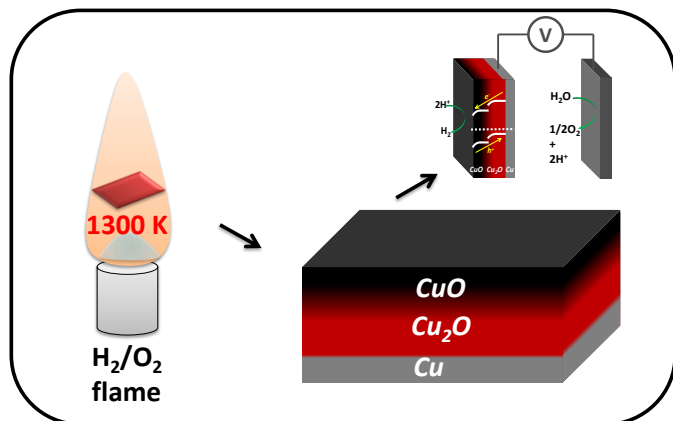


Fig. 4 Current-time curves (a) and current decay curves (b) of composite $\text{Cu}_2\text{O}/\text{CuO}$ photocathodes. Electrolyte, 0.5 M Na_2SO_4 aqueous solution with Ar bubbling (pH 6.82); Light source, AM 1.5 G (100 mW cm^{-2}) with a chopping frequency of 0.2 Hz; The potential applied for current-time test, 0 V vs. RHE.

As shown in Fig. 4a, the decay of photocurrents also indicates deactivation process during PEC water reduction process, even for the relatively stable HT-15S electrode. In order to address this concern, we conducted PEC water reduction test with the participation of O_2 , which was reported to have impressive effect on the cathodic current of pure Cu_2O photocathode³³. The photocurrent and stability of HT-15S measured in air atmosphere is slightly improved compared with that in Ar atmosphere (Fig. S3). Compared with the self-healing process observed for the CuRhO_2 ³⁴ and the impressively improved photocurrent on Cu_2O photocathodes³³ under air atmosphere, the improvement of PEC performance on HT-15S is negligible. This means that the self-healing or O_2 reduction process is negligible for the HT-15S electrode, demonstrating the reduction process from Cu_2O to Cu can be mostly prohibited by the coverage of CuO .

We then conducted PEC measurement on HT-15S in Ar atmosphere for three times. The photocurrent decayed as the PEC measurement prolonged (Fig. S4). To understand the reason for the decay of the current, Raman spectroscopy of HT-15S electrode is measured after PEC measurement (Fig. S5). The dominated phase for all the tested electrodes is CuO . However, the characteristic peaks of CuO for the tested electrodes get broaden and weaken and shift towards a low wavenumber compared with these for the pristine HT-15S electrode. This indicates that the crystallinity of CuO is getting worse during the PEC measurement^{35, 36}. In the meantime,

the characteristic peak of Cu_2O appears after PEC test, manifesting the evolution of a small amount of Cu_2O with on the surface. The decreased crystallinity of CuO and the presence of Cu_2O on the electrode surface indicate that Cu(II) is transforming to Cu(I) during the PEC process. Therefore, the deactivation of as-prepared photocathode is ascribed to the reduction of CuO on the surface.



Scheme 1 Preparation and structure of $\text{Cu}_2\text{O}/\text{CuO}$ composite photocathode in PEC water reduction reaction.

Conclusions

In summary, we presented a facile method to prepare $\text{Cu}_2\text{O}/\text{CuO}$ composite photocathode by one-step heating treatment at ca. 1300 K via $\text{H}_2\text{-O}_2$ flame. The as-prepared samples consist of Cu_2O as the dominant oxide phase on the internal surface and CuO as the minor oxide phase on the external surface. The thickness of the composite oxide layers was increased by prolonging the heating duration and an intimate junction was formed between the (110) plane of Cu_2O and the (111) plane of CuO . The as-prepared composite $\text{Cu}_2\text{O}/\text{CuO}$ photocathode shows improved PEC stability due to the protection of Cu_2O by the outer CuO layer.

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Notes and references

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† Electronic Supplementary Information (ESI) available: Experimental details for preparation, characterization, photoelectrochemical measurement, cross-sectional SEM images and UV-visible diffuse reflectance spectra for all the samples. See DOI: 10.1039/c000000x/

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